

EN - For pricing and availability in your local country please visit one of the below links:

DE - Informationen zu Preisen und Verfügbarkeit in Ihrem Land erhalten Sie über die unten aufgeführten Links:

FR - Pour connaître les tarifs et la disponibilité dans votre pays, cliquez sur l'un des liens suivants:

[TCA785HKLA1](#)

EN

This Datasheet is presented by
the manufacturer

DE

Dieses Datenblatt wird vom
Hersteller bereitgestellt

FR

Cette fiche technique est
présentée par le fabricant

Phase Control IC

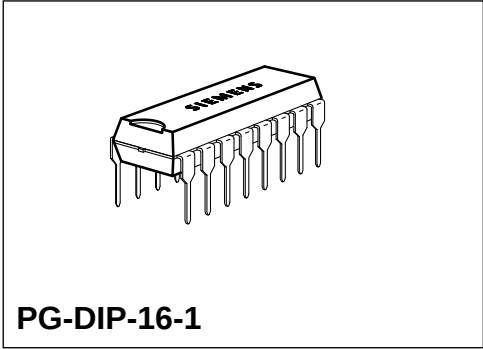
TCA 785

Pb-free lead plating; RoHS compliant

Bipolar IC

Features

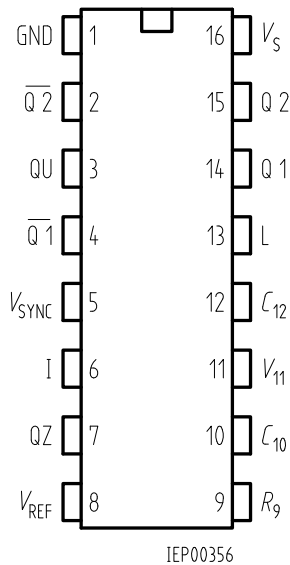
-
- Large application scope
- May be used as zero point switch
-
- Three-phase operation possible (3 ICs)
- Output current 250 mA
- Large ramp current range
- Wide temperature range



Type	Ordering Code	Package
TCA 785	Q67000-A2321	PG-DIP-16-1

This phase control IC is intended to control thyristors, triacs, and transistors. The trigger pulses can be shifted within a phase angle between 0 ° and 180 °. Typical applications include converter circuits, AC controllers and three-phase current controllers.

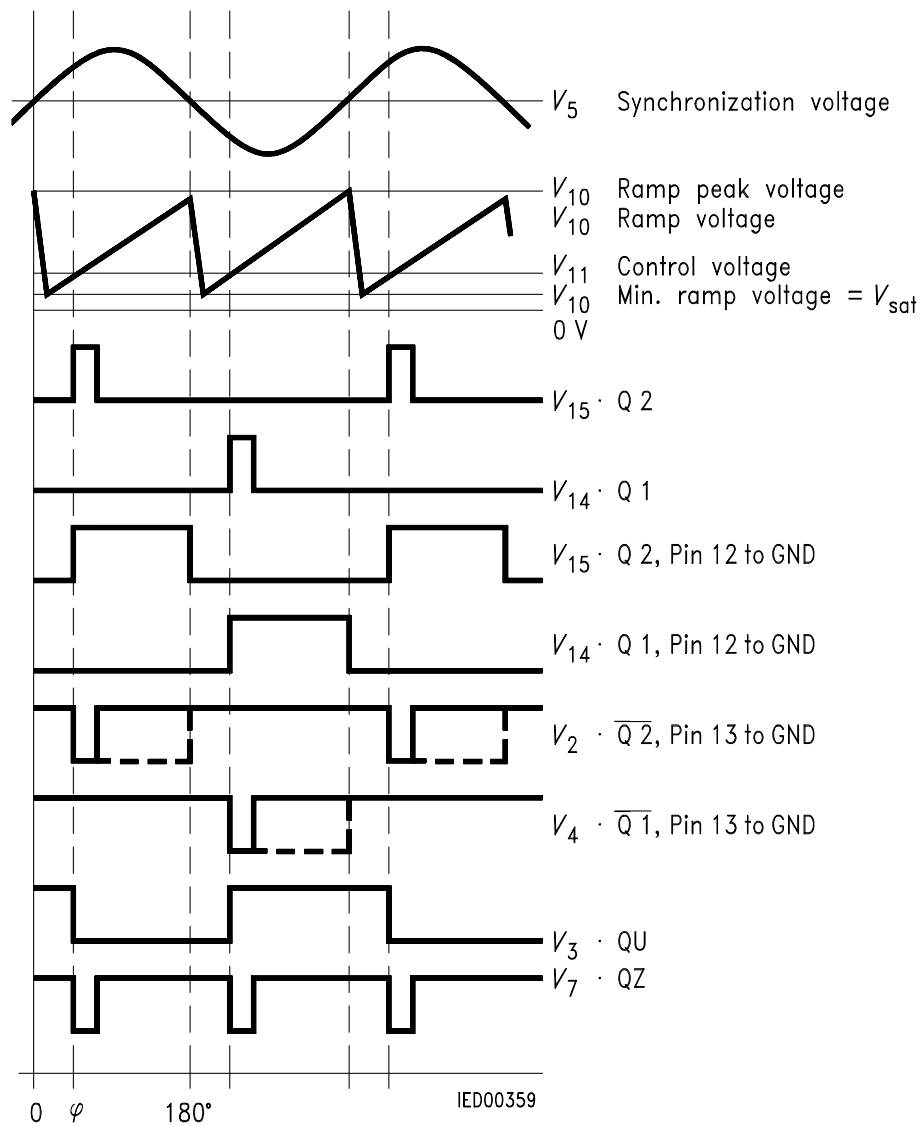
This IC replaces the previous types TCA 780 and TCA 780 D.



Pin Configuration (top view)

Pin Definitions and Functions

Pin	Symbol	Function
1	GND	Ground
2	$\overline{Q2}$	Output 2 inverted
3	$\overline{Q U}$	Output U
4	$\overline{Q2}$	Output 1 inverted
5	V_{SYNC}	Synchronous voltage
6	I	Inhibit
7	Q Z	Output Z
8	V_{REF}	Stabilized voltage
9	R_9	Ramp resistance
10	C_{10}	Ramp capacitance
11	V_{11}	Control voltage
12	C_{12}	Pulse extension
13	L	Long pulse
14	Q 1	Output 1
15	Q 2	Output 2
16	V_S	Supply voltage



Pulse Diagram

Absolute Maximum Ratings

Parameter	Symbol	Limit Values		Unit
		min.	max.	
Supply voltage	V_S	– 0.5	18	V
Output current at pin 14, 15	I_Q	– 10	400	mA
Inhibit voltage	V_6	– 0.5	V_S	V
Control voltage	V_{11}	– 0.5	V_S	V
Voltage short-pulse circuit	V_{13}	– 0.5	V_S	V
Synchronization input current	V_5	– 200	± 200	μA
Output voltage at pin 14, 15	V_Q		V_S	V
Output current at pin 2, 3, 4, 7	I_Q		10	mA
Output voltage at pin 2, 3, 4, 7	V_Q		V_S	V
Junction temperature	T_j		150	$^{\circ}\text{C}$
Storage temperature	T_{stg}	– 55	125	$^{\circ}\text{C}$
Thermal resistance system - air	$R_{\text{th SA}}$		80	K/W

Operating Range

Supply voltage	V_S	8	18	V
Operating frequency	f	10	500	Hz
Ambient temperature	T_A	– 25	85	$^{\circ}\text{C}$

Characteristics

$8 \leq V_S \leq 18 \text{ V}$; $-25^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$; $f = 50 \text{ Hz}$

Parameter	Symbol	Limit Values			Unit	Test Circuit
		min.	typ.	max.		
Supply current consumption S1 ... S6 open $V_{11} = 0 \text{ V}$ $C_{10} = 47 \text{ nF}$; $R_9 = 100 \text{ k}\Omega$	I_S	4.5	6.5	10	mA	1
Synchronization pin 5 Input current R_2 varied	$I_{5 \text{ rms}}$	30		200	μA	1
Offset voltage	ΔV_5		30	75	mV	4
Control input pin 11 Control voltage range	V_{11}	0.2		$V_{10 \text{ peak}}$	V	1
Input resistance	R_{11}		15		$\text{k}\Omega$	5
Semiconductor Group		4				

Characteristics (cont'd)

$8 \leq V_S \leq 18 \text{ V}$; $-25^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$; $f = 50 \text{ Hz}$

Parameter	Symbol	Limit Values			Unit	Test Circuit
		min.	typ.	max.		
Ramp generator						
Charge current	I_{10}	10		1000	μA	
Max. ramp voltage	V_{10}			$V_2 - 2$	V	1
Saturation voltage at capacitor	V_{10}	100	225	350	mV	1.6
Ramp resistance	R_9	3		30	$\text{k}\Omega$	1
Sawtooth return time	t_f		80		μs	1
Inhibit pin 6						
switch-over of pin 7						
Outputs disabled	V_{6L}		3.3	2.5	V	1
Outputs enabled	V_{6H}	4	3.3		V	1
Signal transition time	t_r	1		5	μs	1
Input current	I_{6H}		500	800	μA	1
$V_6 = 8 \text{ V}$						
Input current	$-I_{6L}$	80	150	20	μA	1
$V_6 = 1.7 \text{ V}$						
Deviation of I_{10}	I_{10}	-5		5	%	1
$R_9 = \text{const.}$						
$V_S = 12 \text{ V}$; $C_{10} = 47 \text{ nF}$						
Deviation of I_{10}	I_{10}	-20		20	%	1
$R_9 = \text{const.}$						
$V_S = 8 \text{ V to } 18 \text{ V}$						
Deviation of the ramp voltage between 2 following half-waves, $V_S = \text{const.}$	$\Delta V_{10 \text{ max}}$		± 1		%	
Long pulse switch-over pin 13						
switch-over of S8						
Short pulse at output	V_{13H}	3.5	2.5		V	1
Long pulse at output	V_{13L}		2.5	2	V	1
Input current	I_{13H}			10	μA	1
$V_{13} = 8 \text{ V}$						
Input current	$-I_{13L}$	45	65	10	μA	1
$V_{13} = 1.7 \text{ V}$						
Outputs pin 2, 3, 4, 7						
Reverse current	I_{CEO}			10	μA	2.6
$V_Q = V_S$						
Saturation voltage	V_{sat}	0.1	0.4	2	V	2.6
$I_Q = 2 \text{ mA}$						

Characteristics (cont'd)

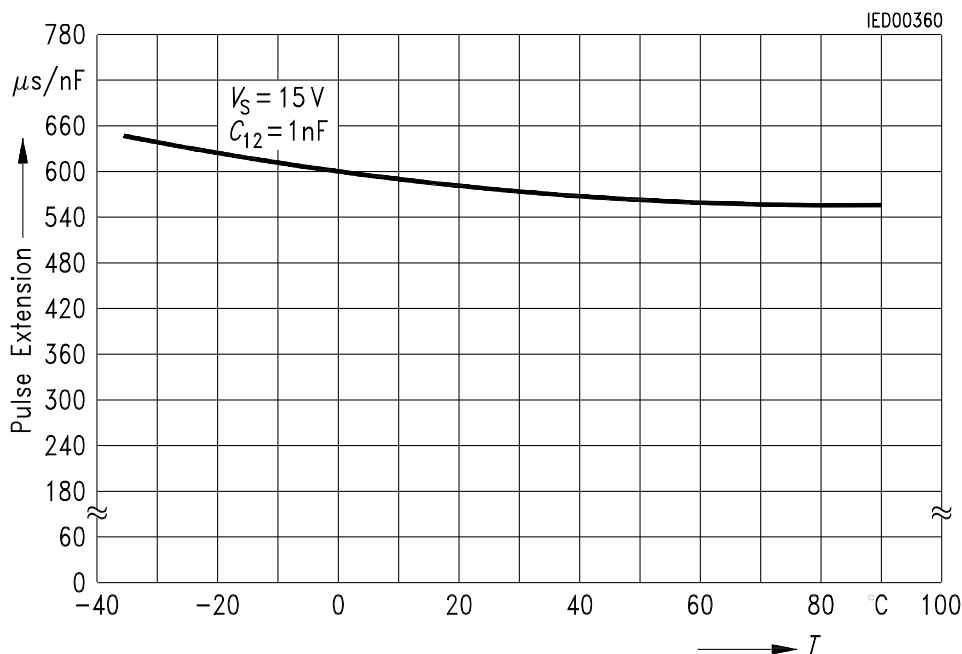
$8 \leq V_S \leq 18 \text{ V}$; $-25^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$; $f = 50 \text{ Hz}$

Parameter	Symbol	Limit Values			Unit	Test Circuit
		min.	typ.	max.		
Outputs pin 14, 15						
H-output voltage – $I_Q = 250 \text{ mA}$	$V_{14/15 \text{ H}}$	$V_S - 3$	$V_S - 2.5$	$V_S - 1.0$	V	3.6
L-output voltage $I_Q = 2 \text{ mA}$	$V_{14/15 \text{ L}}$	0.3	0.8	2	V	2.6
Pulse width (short pulse) S9 open	t_p	20	30	40	μs	1
Pulse width (short pulse) with C_{12}	t_p	530	620	760	$\mu\text{s}/\text{nF}$	1
Internal voltage control						
Reference voltage	V_{REF}	2.8	1	3.1	3.4	V
Parallel connection of 10 ICs possible						
TC of reference voltage	α_{REF}			2×10^{-4}	5×10^{-4}	1/K

Application Hints for External Components

		min		max	
Ramp capacitance	C_{10}	500 pF		$1 \mu\text{F}^{1)}$	The minimum and maximum values of I_{10} are to be observed
Triggering point	$t_{Tr} =$	$\frac{V_{11} \times R_9 \times C_{10}}{V_{REF} \times K}$ ²⁾			
Charge current	$I_{10} =$	$\frac{V_{REF} \times K}{R_9}$ ²⁾			
				Ramp voltage	
				$V_{10 \max} = V_S - 2 \text{ V}$	$V_{10} = \frac{V_{REF} \times K \times t}{R_9 \times C_{10}}$ ²⁾

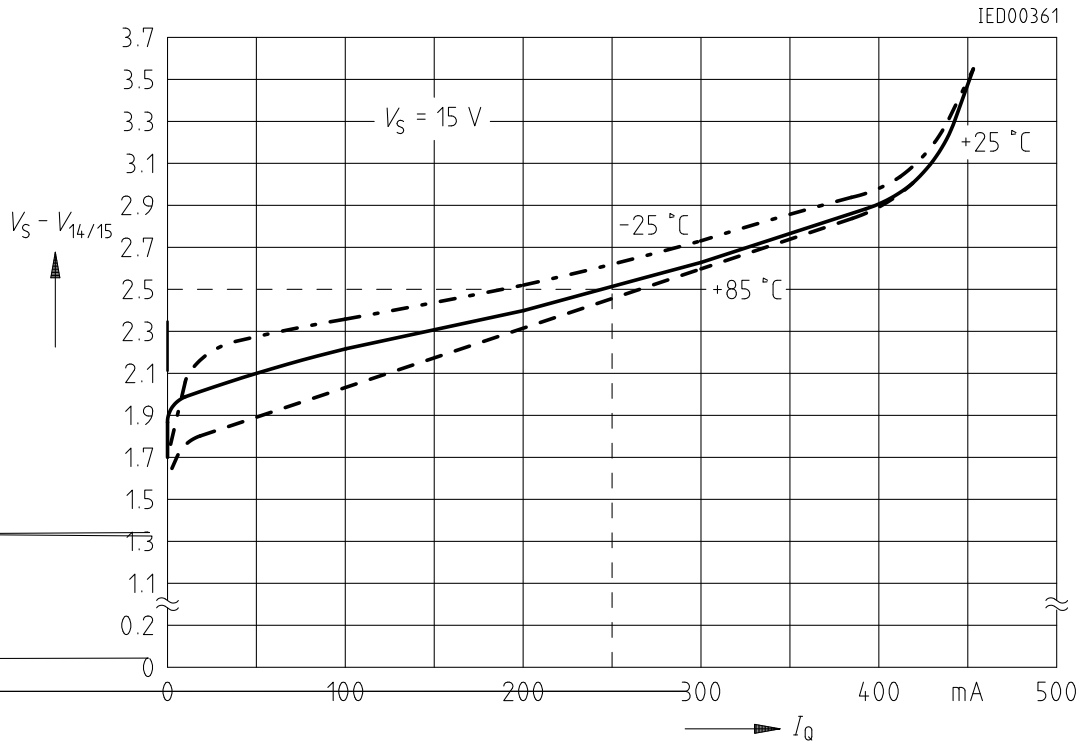
Pulse Extension versus Temperature



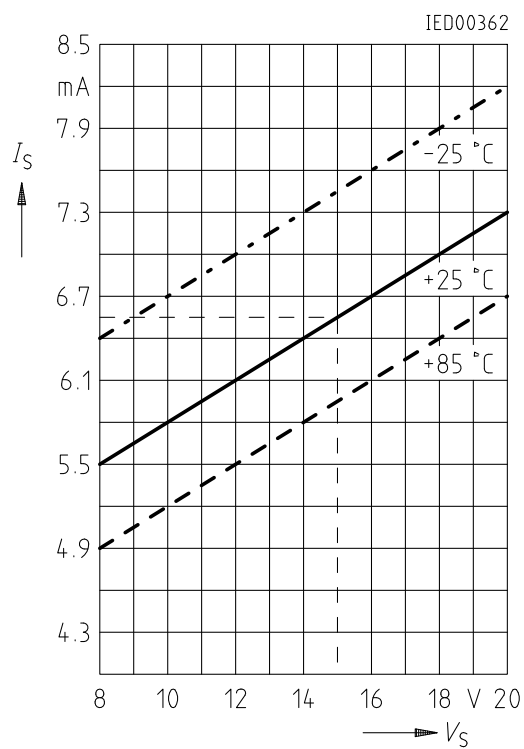
¹⁾ Attention to flyback times

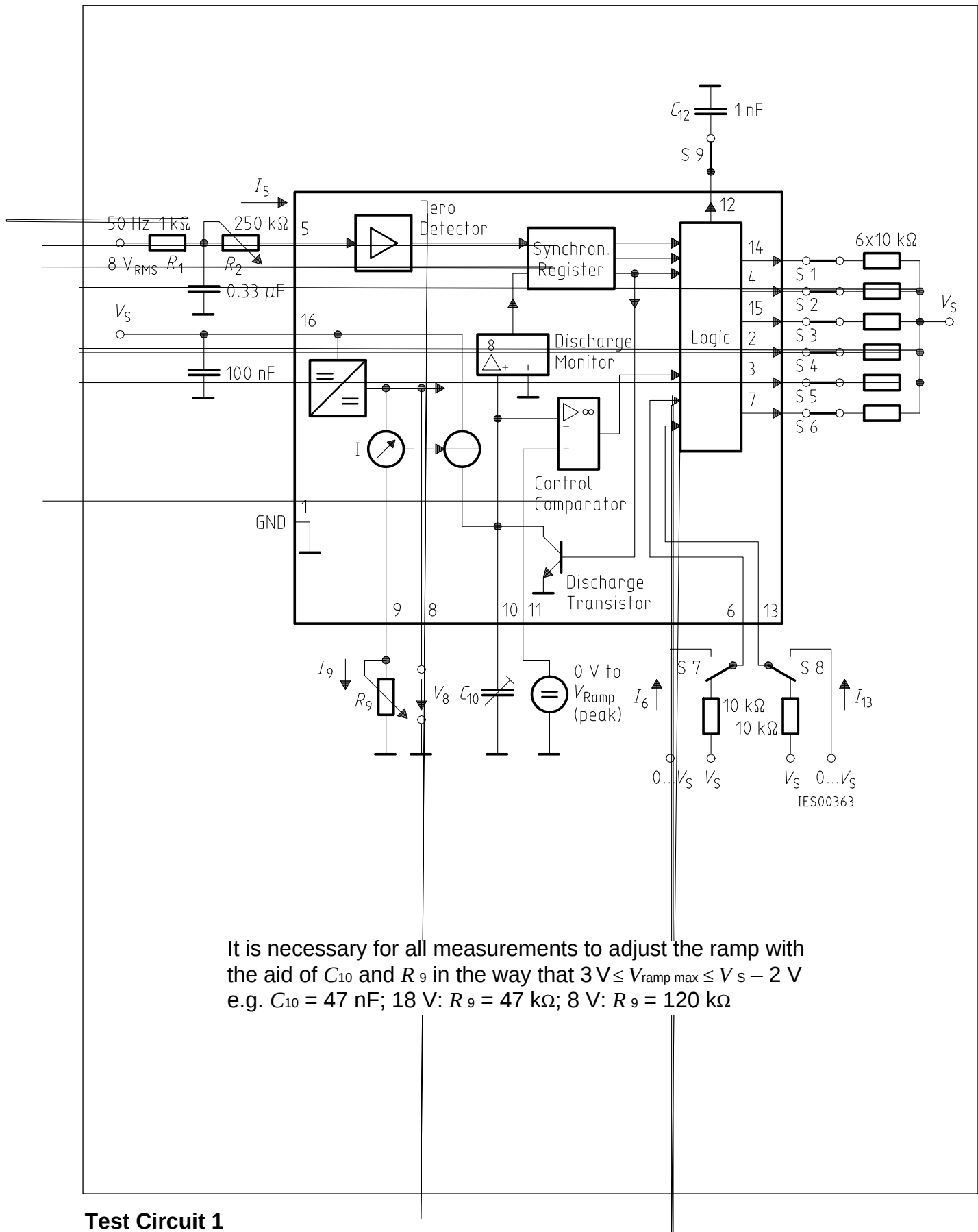
²⁾ $K = 1.10 \pm 20 \%$

Output Voltage measured to + V_S

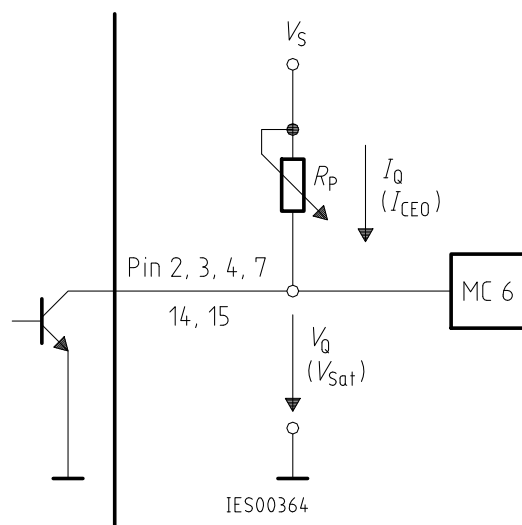


Supply Current versus Supply Voltage



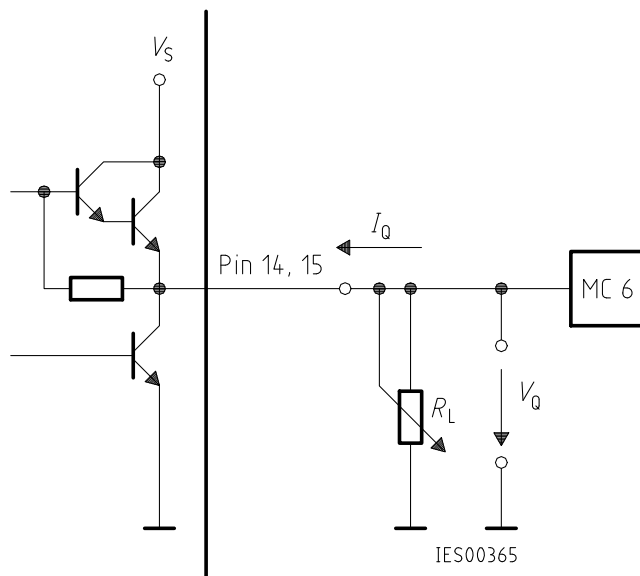


Test Circuit 1



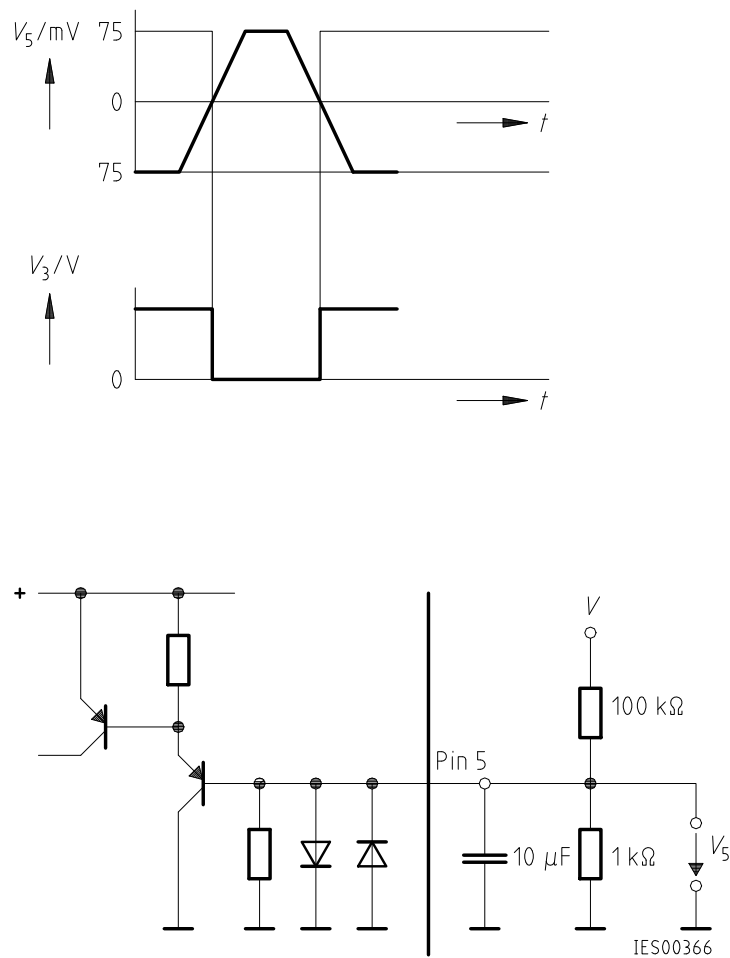
The remaining pins are connected as in test circuit 1

Test Circuit 2



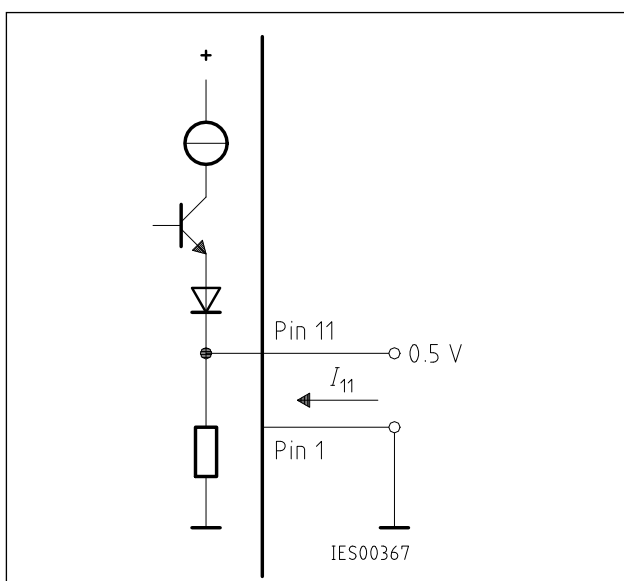
The remaining pins are connected as in test circuit 1

Test Circuit 3

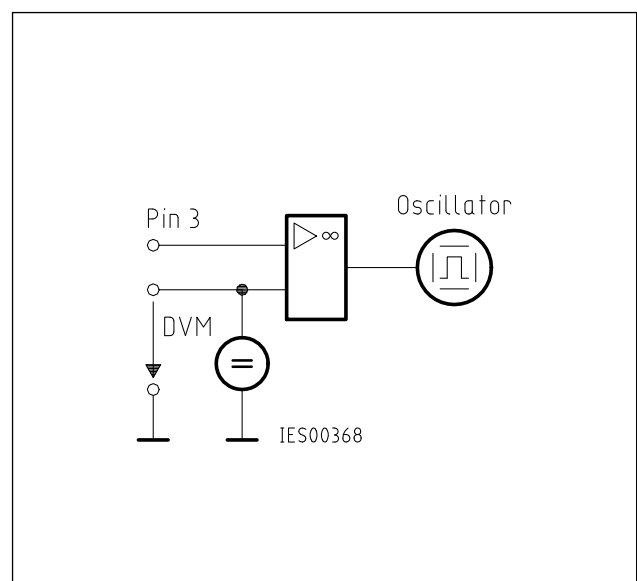


Remaining pins are connected as in test circuit 1
The 10 μF capacitor at pin 5 serves only for test purposes

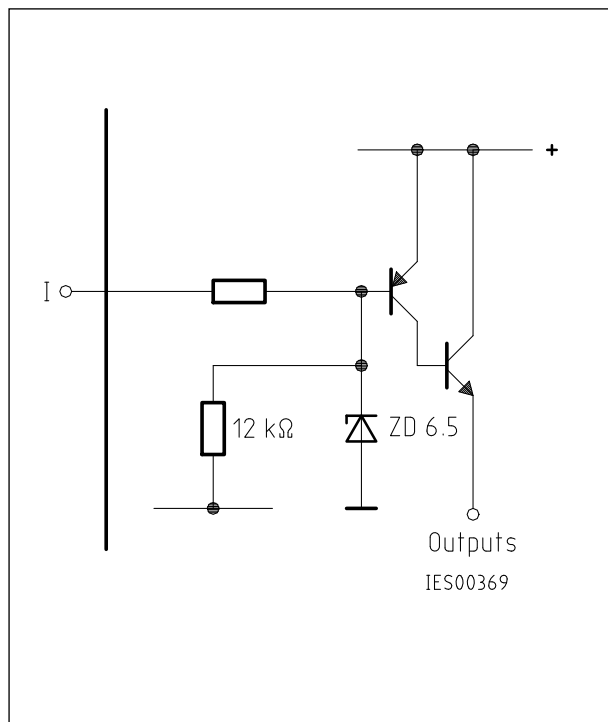
Test Circuit 4



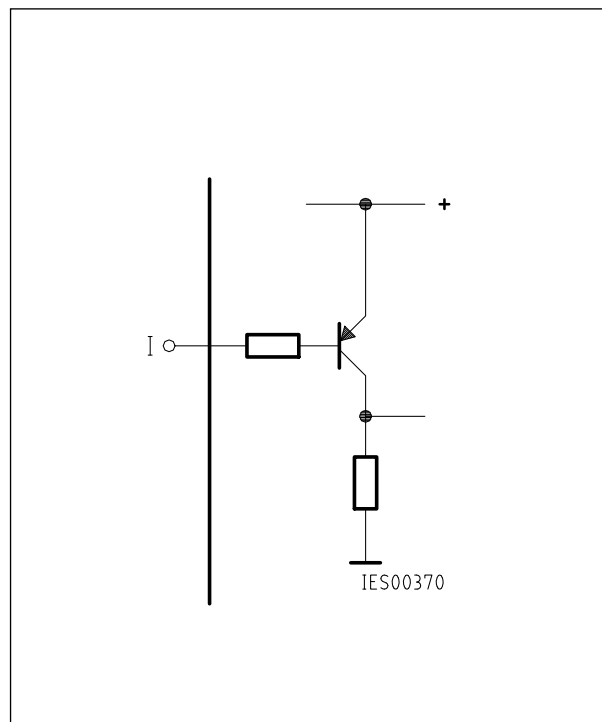
Test Circuit 5



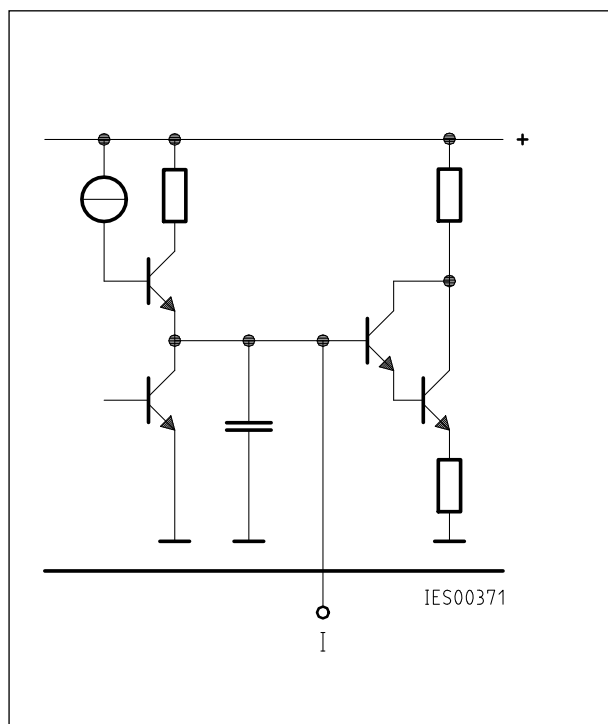
Test Circuit 6



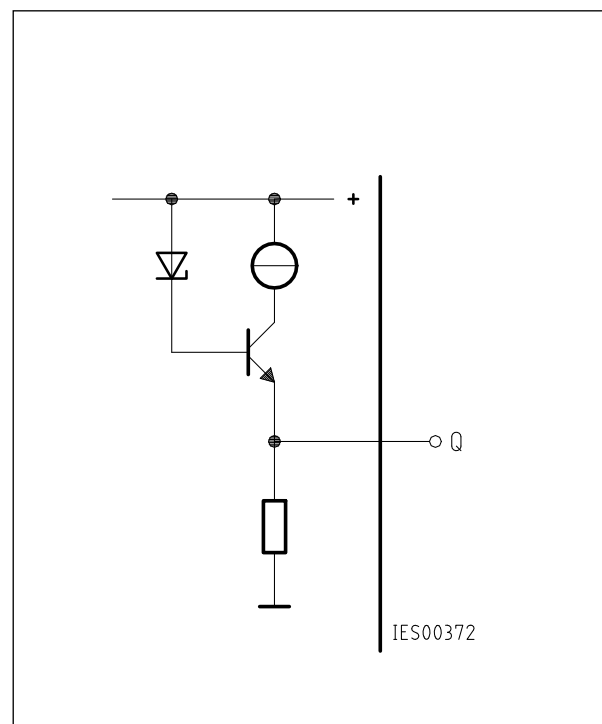
Inhibit 6



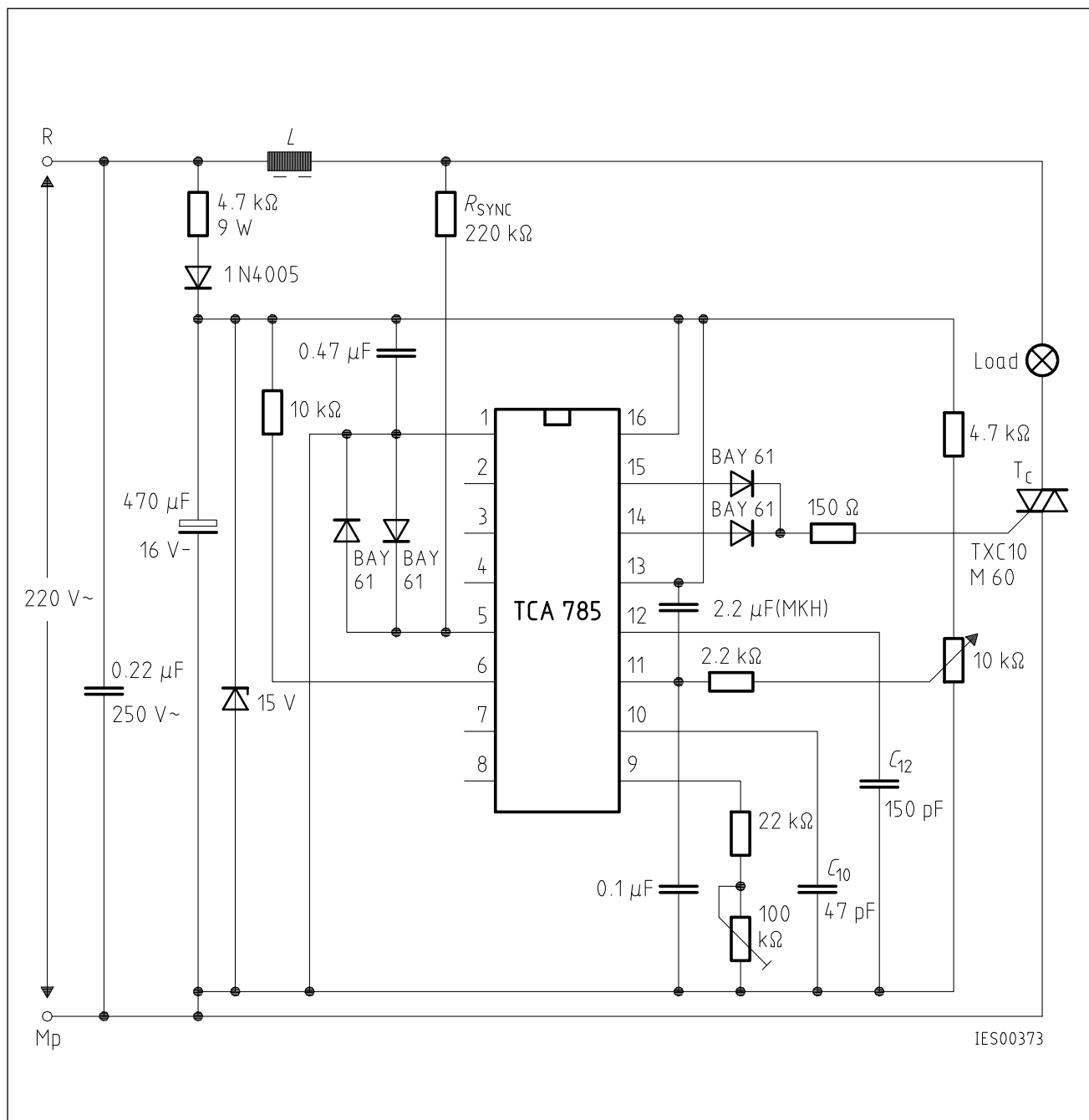
Long Pulse 13



Pulse Extension 12



Reference Voltage 8



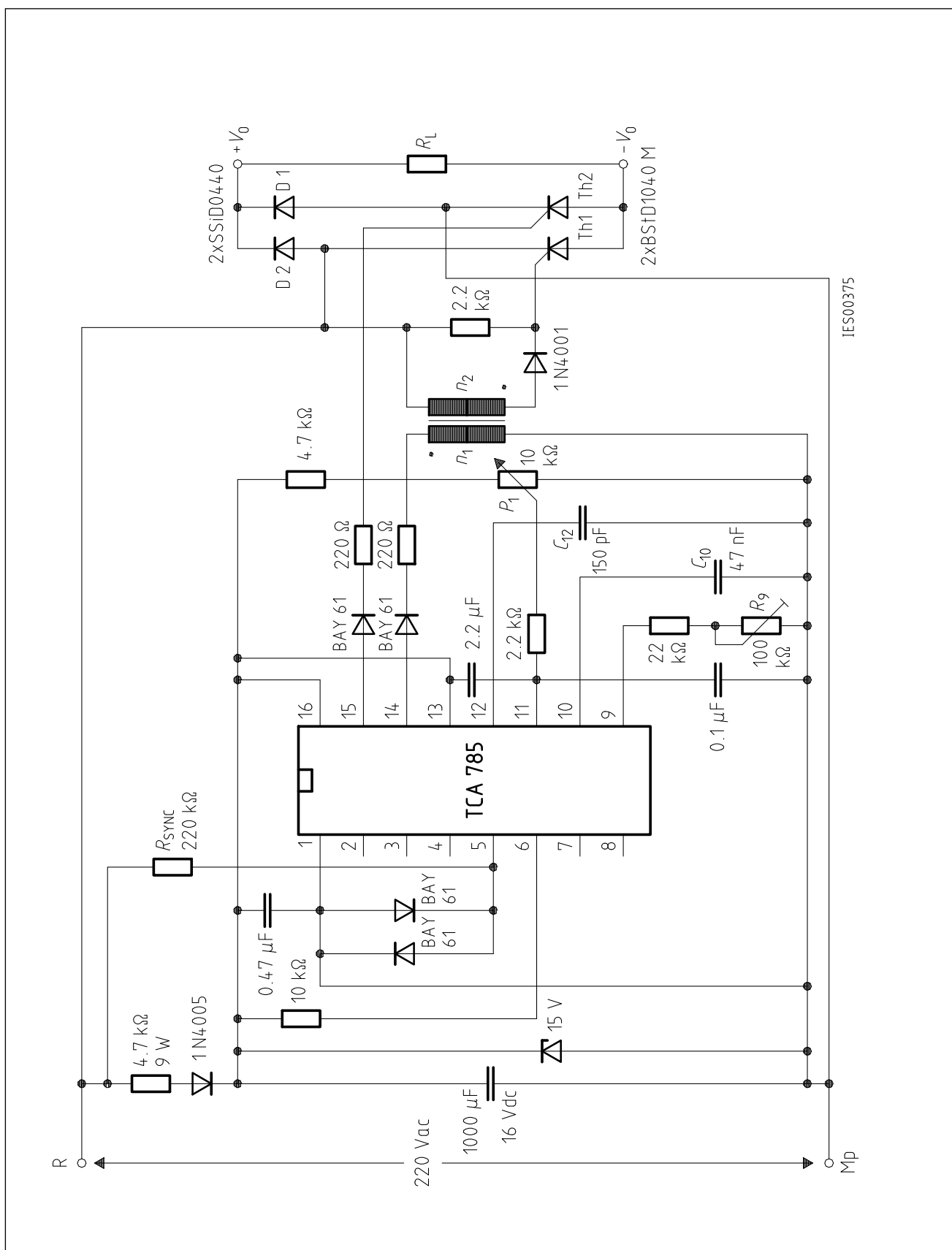
Application Examples

Triac Control for up to 50 mA Gate Trigger Current

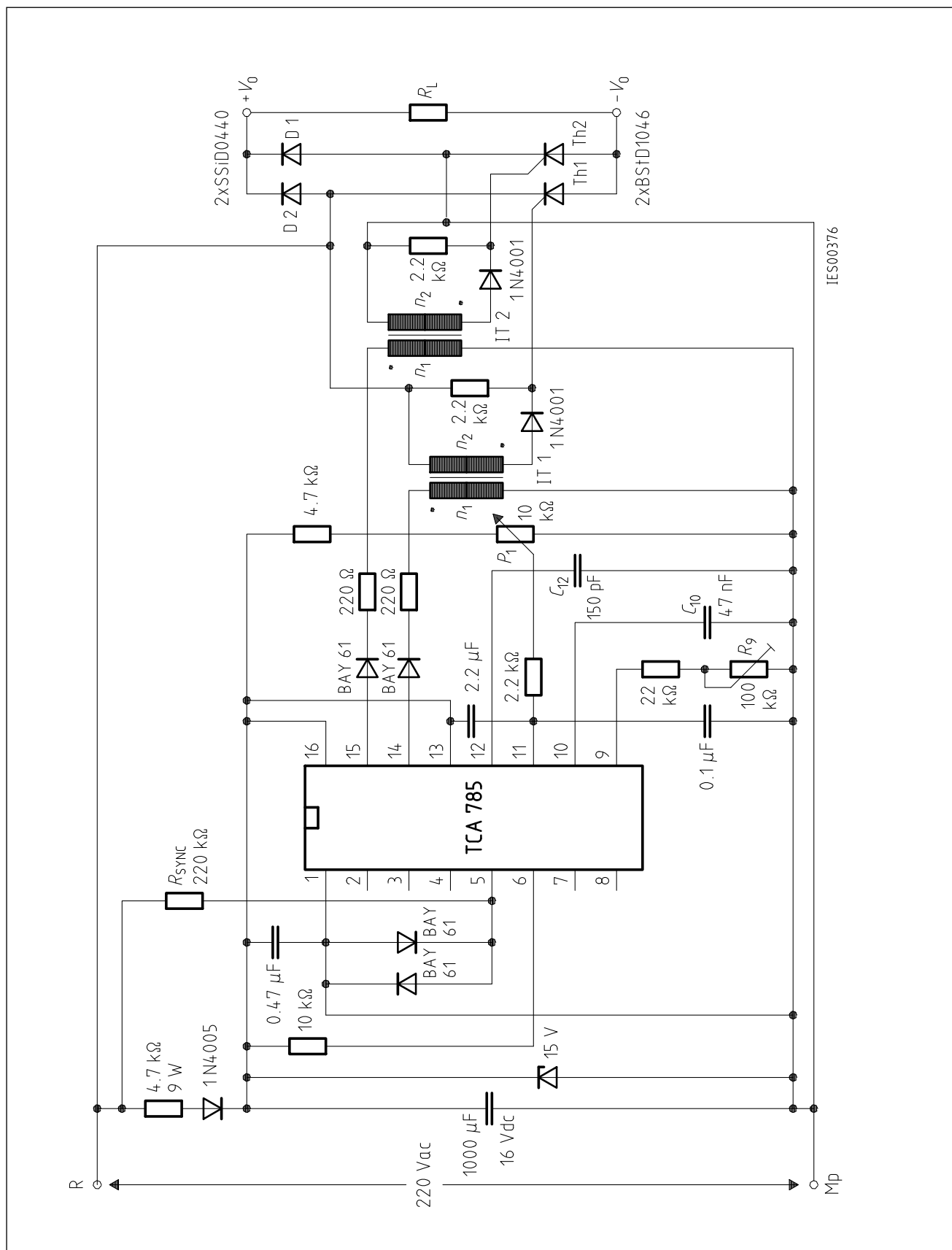
A phase control with a directly controlled triac is shown in the figure. The triggering angle of the triac can be adjusted continuously between 0° and 180° with the aid of an external potentiometer. During the positive half-wave of the line voltage, the triac receives a positive gate pulse from the IC output pin 15. During the negative half-wave, it also receives a positive trigger pulse from pin 14. The trigger pulse width is approx. $100\text{ }\mu\text{s}$.



Semiconductor Group



Half-Controlled Single-Phase Bridge Circuit with Trigger Pulse Transformer and Direct Control for Low-Power Thyristors



Half-Controlled Single-Phase Bridge Circuit with Two Trigger Pulse Transformers for Low-Power Thyristors

EN - For pricing and availability in your local country please visit one of the below links:

DE - Informationen zu Preisen und Verfügbarkeit in Ihrem Land erhalten Sie über die unten aufgeführten Links:

FR - Pour connaître les tarifs et la disponibilité dans votre pays, cliquez sur l'un des liens suivants:

[TCA785HKLA1](#)

EN

This Datasheet is presented by
the manufacturer

DE

Dieses Datenblatt wird vom
Hersteller bereitgestellt

FR

Cette fiche technique est
présentée par le fabricant